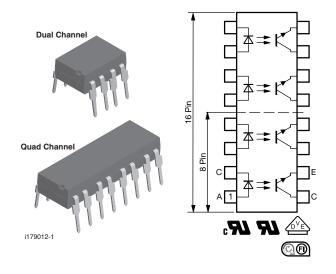




Vishay Semiconductors

# **Optocoupler, Phototransistor Output, (Dual, Quad Channel)**



#### LINKS TO ADDITIONAL RESOURCES



#### DESCRIPTION

The TCET2100, TCET4100 consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode, available in 8 pin (dual channel) and 16 pin (quad

channel) package.

#### FEATURES

- Extra low coupling capacity typical 0.2 pF
- High common mode rejection
- Low temperature coefficient of CTR
- Rated impulse voltage (transient overvoltage) V<sub>IOTM</sub> = 10 kV peak



RoHS

COMPLIANT

- Creepage current resistance according to VDE 0303 / IEC 60112 comparative tracking index: CTI ≥ 175
- Thickness through insulation  $\ge 0.4$  mm
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### AGENCY APPROVALS

- <u>UL</u>
- <u>cUL</u>
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO

ORDERING INFORMATION	
T C E	T     #     1     0     0       PART NUMBER
AGENCY CERTIFIED / PACKAGE	CTR (%)
UL, cUL, VDE	50 to 600
DIP-8, dual channel	TCET2100
DIP-16, quad channel	TCET4100



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# TCET2100, TCET4100

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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
INPUT		· · ·		•	
Reverse voltage		V <sub>R</sub>	6	V	
Forward current		I <sub>F</sub>	60	mA	
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	1.5	A	
Power dissipation		P <sub>diss</sub>	100	mW	
Junction temperature		Tj	125	°C	
OUTPUT					
Collector emitter voltage		V <sub>CEO</sub>	70	V	
Emitter collector voltage		V <sub>ECO</sub>	7	V	
Collector current		Ι <sub>C</sub>	50	mA	
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA	
Power dissipation		P <sub>diss</sub>	150	mW	
Junction temperature		Tj	125	°C	
COUPLER					
Total power dissipation		P <sub>tot</sub>	250	mW	
Operating ambient temperature range		T <sub>amb</sub>	-55 to +100	°C	
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C	
Soldering temperature <sup>(1)</sup>	2 mm from case, t $\leq$ 10 s	T <sub>sld</sub>	260	°C	

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to wave profile for soldering conditions for through hole devices.

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = \pm 50 \text{ mA}$	V <sub>F</sub>	-	1.25	1.6	V
Junction capacitance	$V_R = 0 V, f = 1 MHz$	Cj	-	50	-	pF
OUTPUT						
Collector emitter voltage	$I_{\rm C} = 1  \rm{mA}$	V <sub>CEO</sub>	70	-	-	V
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7	-	-	V
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I <sub>CEO</sub>	-	10	100	nA
COUPLER						
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA	V <sub>CEsat</sub>	-	-	0.3	V
Cut-off frequency	$V_{CE}$ = 5 V, I <sub>F</sub> = 10 mA, R <sub>L</sub> = 100 $\Omega$	f <sub>c</sub>	-	110	-	kHz
Coupling capacitance	f = 1 MHz	C <sub>k</sub>	-	0.3	-	pF

Note

• Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
I <sub>C</sub> /I <sub>F</sub>	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 5 \text{ mA}$	CTR	50	-	600	%

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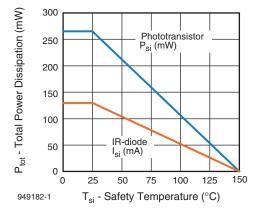


Fig. 1 - Derating Diagram

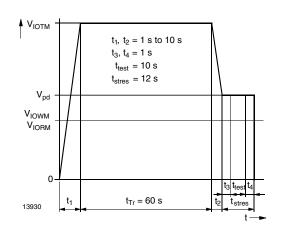


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-5/DIN EN 60747-; IEC60747

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>d</sub>	-	3	-	μs
Rise time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>r</sub>	-	3	-	μs
Turn-on time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>on</sub>	-	6	-	μs
Storage time	$V_{S}$ = 5 V, $I_{C}$ = 2 mA, $R_{L}$ = 100 $\Omega$ , (see Fig. 3)	t <sub>s</sub>	-	0.3	-	μs
Fall time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see Fig. 3)	t <sub>f</sub>	-	4.7	-	μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ , (see Fig. 3)	t <sub>off</sub>	-	5	-	μs
Turn-on time	$V_S = 5 \text{ V}, \text{ I}_F = 10 \text{ mA}, \text{ R}_L = 1 \text{ k}\Omega$ , (see Fig. 4)	t <sub>on</sub>	-	9	-	μs
Turn-off time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 k\Omega, (see Fig. 4)	t <sub>off</sub>	-	10	-	μs

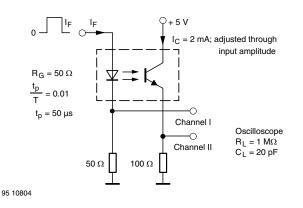


Fig. 3 - Test Circuit, Non-Saturated Operation

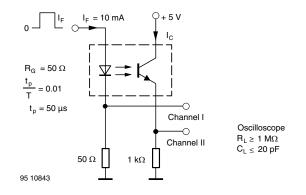
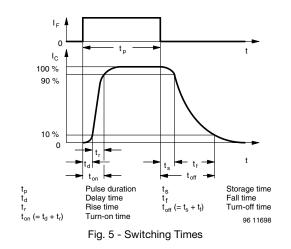


Fig. 4 - Test Circuit, Saturated Operation



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SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification	According to IEC 68 part 1		55 / 100 / 21			
Comparative tracking index		CTI	175			
Maximum rated withstanding isolation voltage	t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>		
Maximum transient isolation voltage		V <sub>IOTM</sub>	10 000	V <sub>peak</sub>		
Maximum repetitive peak isolation voltage		V <sub>IORM</sub>	890	V <sub>peak</sub>		
	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω		
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω		
	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 150 °C (construction test only)	R <sub>IO</sub>	≥ 10 <sup>9</sup>	Ω		
Output safety power		P <sub>SO</sub>	400	mW		
Input safety current		I <sub>SI</sub>	275	mA		
Safety temperature		Ts	175	°C		
Creepage distance			≥7	mm		
Clearance distance			≥7	mm		
Insulation thickness		DTI	≥ 0.4	mm		
Partial discharge test voltage - routine test	100 %, t <sub>test</sub> = 1 s	V <sub>pd</sub>	1.669	kV <sub>peak</sub>		
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s}, (see Fig. 2)$	V <sub>pd</sub>	1.424	kV <sub>peak</sub>		

Note

• As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



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#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

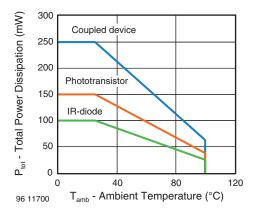


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

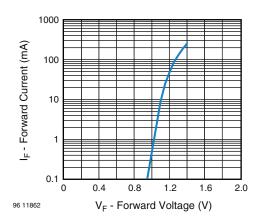


Fig. 7 - Forward Current vs. Forward Voltage

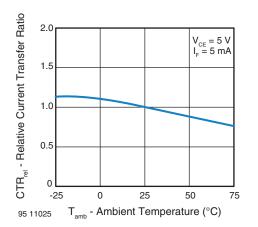


Fig. 8 - Relative Current Transfer Ratio vs. Ambient Temperature

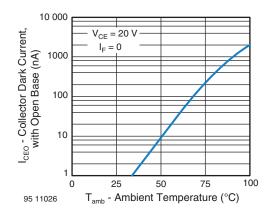


Fig. 9 - Collector Dark Current vs. Ambient Temperature

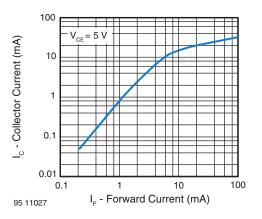


Fig. 10 - Collector Current vs. Forward Current

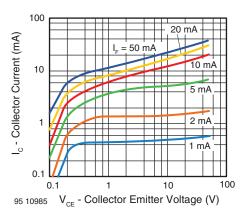


Fig. 11 - Collector Current vs. Collector Emitter Voltage

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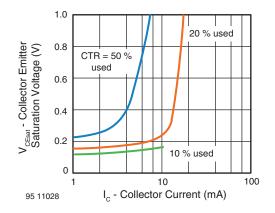


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

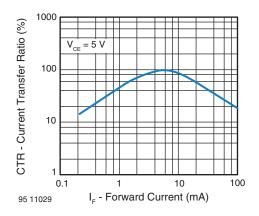


Fig. 13 - Current Transfer Ratio vs. Forward Current

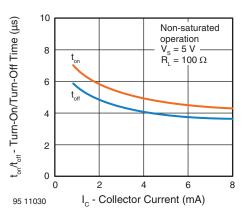


Fig. 14 - Turn-on/off Time vs. Collector Current

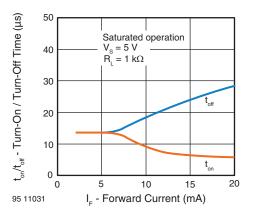
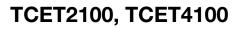


Fig. 15 - Turn-On / Turn-Off Time vs. Forward Current

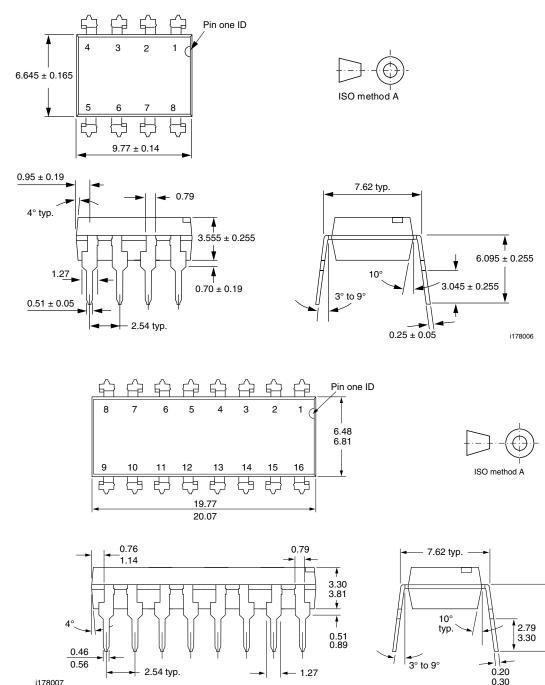




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## **Vishay Semiconductors**

#### **PACKAGE DIMENSIONS** in millimeters



i178007

#### **PACKAGE MARKING** (example)

O TCET2100
$\bigtriangleup$
V XXXX 68

Note

• XXXX = LMC (lot marking code)

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